HBL5006 Series

LED Shunt

The HBL5006 Series are electronic shunts which provide a current bypass in the case of LEDs going into open circuit. LEDs are by nature quite fragile when subjected to transients and surge conditions. There are also many cases where high reliability of the LED lighting must be maintained such as in headlights, lighthouses, bridges, aircraft, runways and so forth. In these cases the low cost addition of the shunt device will provide full assurance that an entire string of LEDs will not extinguish should one LED fail open. The shunt device is also applicable to other loads where circuit continuity is required. The devices are designed to be used with LED string currents from 50 to 350 mA.

Features

- Protection for the Following IEC Standards:
  IEC 61000−4−2 (Level 4)
  ISO 10605
- Low ESD Clamping Voltage
- Automatically Resets Itself if the LED Heals Itself or is Replaced
- ON−State Voltage Typically 1.1 V
- OFF−State Current less than 1.0 μA
- SZ Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC−Q101 Qualified and PPAP Capable
- These Devices are Pb−Free and are RoHS Compliant

Typical Applications

- LEDs where Preventive Maintenance is Impractical
- LED Headlights in Automobiles
- Automotive LED Applications
- LEDs with High Reliability Requirements
- Crowbar Protection for Open Circuit Conditions
- Overvoltage Protection for Sensitive Circuits

ON Semiconductor®

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MARKING DIAGRAMS

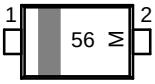


SOD−323
CASE 477





SOD−523
CASE 502

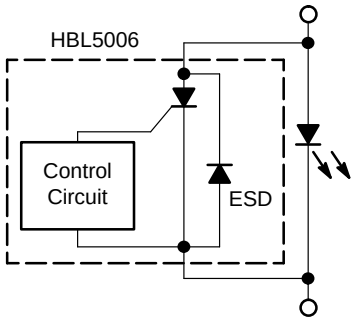


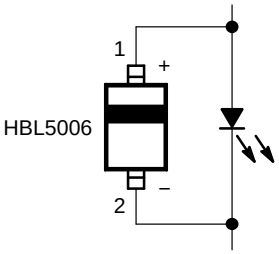


SOD−923
CASE 514AB



XX = Specific Device Code
M = Date Code





Apply heat sinking to pin 2

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

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MAXIMUM RATINGS

Rating		Symbol	Value	Unit
On−State Current, (T_A = 25°C) (Note 2)	SOD−323 (Note 1) SOD−323 (Note 2) SOD−523 (Note 1) SOD−523 (Note 2) SOD−923 (Note 1) SOD−923 (Note 2)	$I_{T(AVG)}$	250 200 300 250 350 300	mA
Thermal Resistance, Junction−to−Air (All Packages)	SOD−323 (Note 1) SOD−323 (Note 2) SOD−523 (Note 1) SOD−523 (Note 2) SOD−923 (Note 1) SOD−923 (Note 2)	θ_{JA}	435 550 360 435 285 360	°C/W
Operating Temperature Range	(Note 3)	T_J	−40 to 150	°C
Non−Operating Temperature Range		T_J	150	°C
Lead Temperature, Soldering (10 Sec)		T_L	260	°C
IEC 61000−4−2 Contact (ESD) IEC 61000−4−2 Air (ESD)		ESD ESD	±15 ±15	kV

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Mounted onto a 2−layer, 1000 mm^2 per layer, 3 oz Cu, FR4 PCB with pin 2 connected to the heat sink and pin 1 only connected to a signal trace. The heat sinking must be connected to pin 2, which is the LED cathode connection.
   Normally this device would be mounted on the same copper heat sink and adjacent to the LED(s). If the LED(s) were to go open, then the HBL shunt would now dissipate the power using the same copper heat sink. Since the shunt has a voltage that is nominally 30% of the LED, then the power dissipation would be much lower, and easily handled by the same heat sink as the LED.
2. Mounted onto a 2−layer, 50 mm^2 per layer, 1 oz Cu, FR4 PCB.
3. Max operating temperature for DC conditions is 150°C, but not to exceed 175°C for pulsed conditions with low duty cycle or non−repetitive.

ELECTRICAL CHARACTERISTICS (Unless otherwise noted: T_A = 25°C)

Symbol	Characteristics	Package	Min	Typ	Max	Unit
V_{BR}	Breakdown Voltage: The minimum voltage across the device in or at the breakdown region. Measured at I_{BR} = 1 mA.	SOD−323	6.2	7.0		V
		SOD−523	6.2	7.0		
		SOD−923	6.2	7.0		
I_H	Holding Current: The minimum current required to maintain the device in the on-state.	SOD−323		25	40	mA
		SOD−523		25	40	
		SOD−923		25	40	
I_L	Latching Current: The minimum current required to turn from the off-state to the on-state.	SOD−323		9.0		mA
		SOD−523		9.0		
		SOD−923		9.0		
V_{BO}	Breakover Voltage: The voltage across the device in the breakover region.	SOD−323	6.5	7.2	8.0	V
		SOD−523	6.5	7.2	8.0	
		SOD−923	6.5	7.2	8.0	
I_R	Off−State Current: The dc value of current that results from the application of the off-state voltage. Measured at 3.3 V.	SOD−323			1.0	μA
		SOD−523			1.0	
		SOD−923			1.0	
V_T	On−State Voltage. Measured at 100 mA.	SOD−323	0.9	1.1	1.3	V
		SOD−523	0.9	1.1	1.3	
		SOD−923	0.9	1.1	1.3	
V_C	Clamping Voltage TLP (Note 4)	SOD−323		6.5 11.2		V
	I_{PP} = 8 A } IEC 6100−4−2 Level 2 equivalent (±4 kV Contact, ±4 kV Air)	SOD−523		6.5 11.2		
	I_{PP} = 16 A } IEC 6100−4−2 Level 4 equivalent (±8 kV Contact, ±15 kV Air)	SOD−923		6.5 11.2		

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

4. ANSI/ESD STM5.5.1 − Electrostatic Discharge Sensitivity Testing using Transmission Line Pulse (TLP) Model TLP conditions: Z_0 = 50 Ω, t_p = 100 ns, t_r = 4 ns, averaging window; t_1 = 30 ns to t_2 = 60 ns.

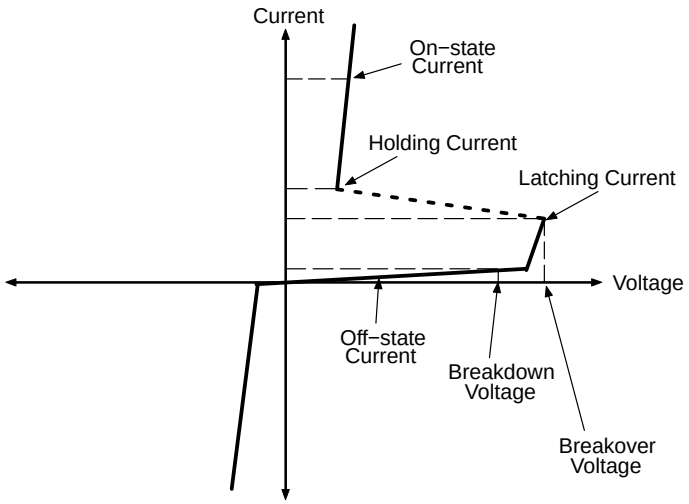


Figure 1. I−V Characteristics

TYPICAL APPLICATION CIRCUIT

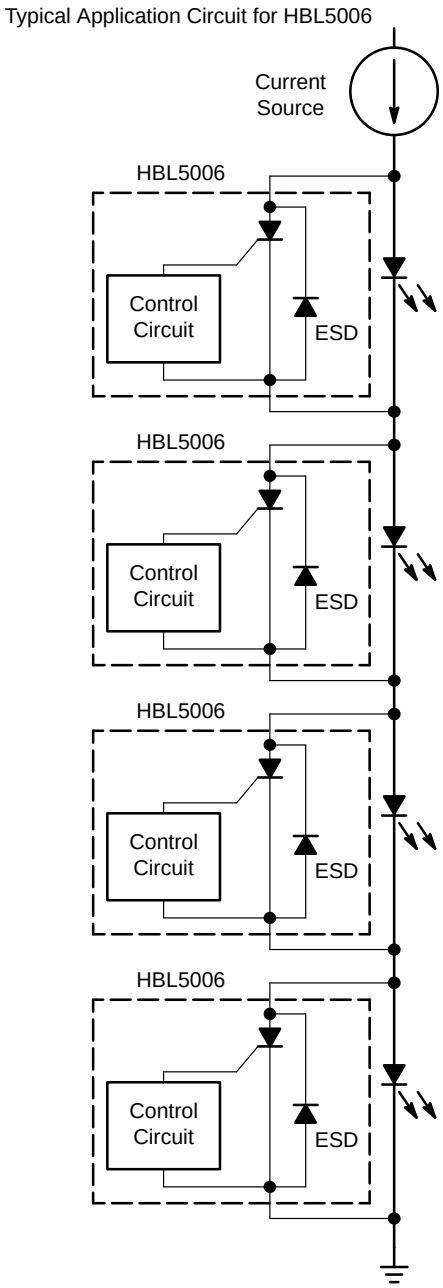


Figure 2. Typical Application Circuit

DEVICE ORDERING INFORMATION

Device	Marking	Package	Shipping†
HBL5006HT1G	HD	SOD−323 (Pb−Free)	3000 / Tape & Reel
SZHBL5006HT1G*	HD		
HBL5006XV2T1G	56	SOD−523 (Pb−Free)	3000 / Tape & Reel
SZHBL5006XV2T1G*	56		
HBL5006XV2T5G	56		8000 / Tape & Reel
SZHBL5006XV2T5G*	56		
HBL5006P2T5G	LD	SOD−923 (Pb−Free)	8000 / Tape & Reel
SZHBL5006P2T5G*	LD		

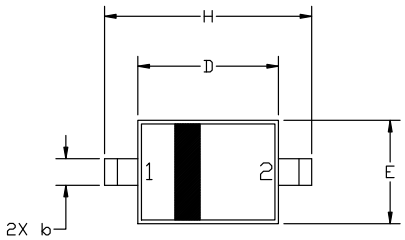
†For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

*SZ Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC−Q101 Qualified and PPAP Capable.

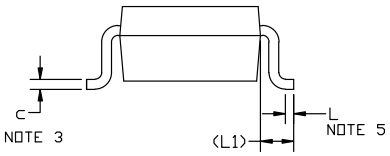


SOD−323 1.70x1.25x0.85
CASE 477
ISSUE K

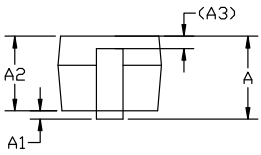
DATE 11 MAR 2024



TOP VIEW



SIDE VIEW

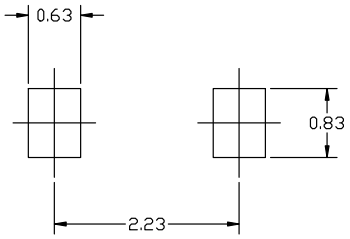


END VIEW

NOTES:

1. DIMENSIONING AND TOLERANCING AS PER ASME Y14.5M, 2018.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. LEAD THICKNESS SPECIFIED PER L/F DRAWING WITH SOLDER PLATING.
4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.
5. DIMENSION L IS MEASURE FROM END OF RADIUS.

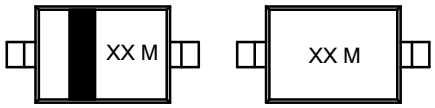
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	MIN.	NOM.	MAX.
A	0.80	0.90	1.00
A1	0.00	0.05	0.10
A2	0.75	0.85	0.95
A3	0.15 (REF)		
b	0.25	0.32	0.4
c	0.09	0.12	0.18
D	1.60	1.70	1.80
E	1.15	1.25	1.35
H	2.30	2.50	2.70
L	0.08	---	---
L1	0.40 (REF)		



RECOMMENDED MOUNTING FOOTPRINT

*For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference manual, SOLDERRM/D.

GENERIC MARKING DIAGRAM*



STYLE 1 STYLE 2

XX = Specific Device Code
M = Date Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, “G” or microdot “▪”, may or may not be present. Some products may not follow the Generic Marking.

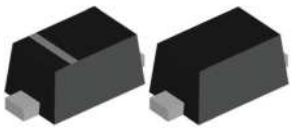
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PIN 1. CATHODE (POLARITY BAND)
2. ANODE

STYLE 2:
NO POLARITY

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DESCRIPTION:	**SOD−323 1.70x1.25x0.85**		**PAGE 1 OF 1**

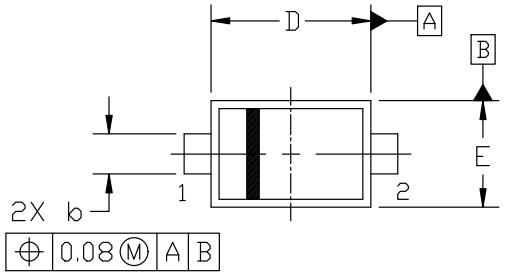
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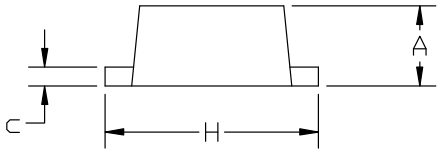


SOD−523 1.20x0.80x0.60
CASE 502
ISSUE F

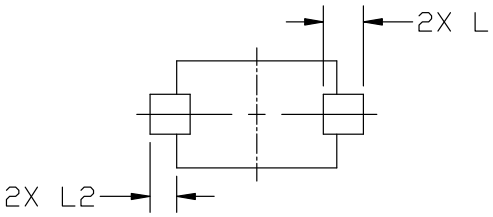
DATE 08 FEB 2024



TOP VIEW



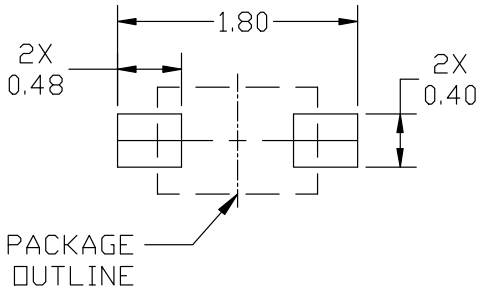
SIDE VIEW



BOTTOM VIEW

NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH, MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

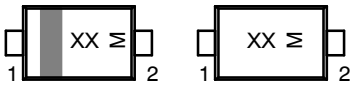
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A	0.50	0.60	0.70
b	0.25	0.30	0.35
c	0.07	0.14	0.20
D	1.10	1.20	1.30
E	0.70	0.80	0.90
H	1.50	1.60	1.70
L	0.30 REF		
L2	0.15	0.20	0.25



RECOMMENDED MOUNTING FOOTPRINT

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference manual, SOLDERRM/D.

GENERIC MARKING DIAGRAM*



STYLE 1 STYLE 2

XX = Specific Device Code
M = Date Code

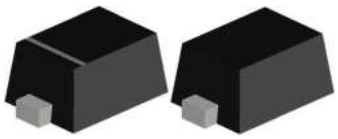
*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, “G” or microdot “▪”, may or may not be present. Some products may not follow the Generic Marking.

STYLE 1:
PIN 1. CATHODE (POLARITY BAND)
2. ANODE

STYLE 2:
NO POLARITY

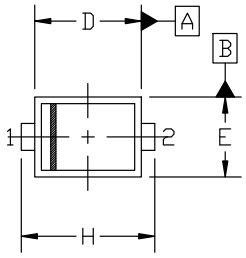
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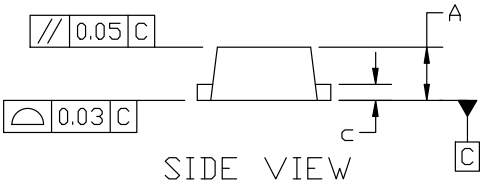


SOD−923 0.80x0.60x0.37
CASE 514AB
ISSUE E

DATE 08 FEB 2024

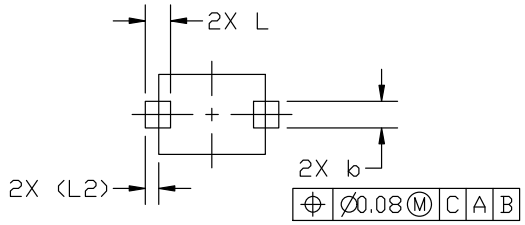


TOP VIEW



SIDE VIEW

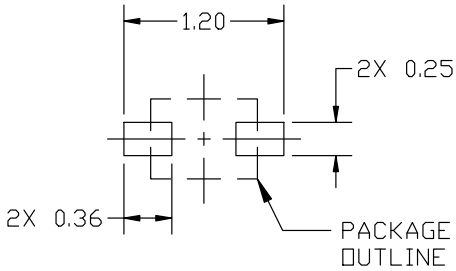
SEATING PLANE



BOTTOM VIEW

NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.
5. DIMENSION L WILL NOT EXCEED 0.30mm.

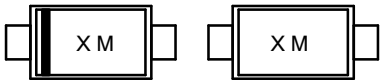
MILLIMETERS			
DIM	MIN.	NOM.	MAX.
A	0.34	0.37	0.40
b	0.15	0.20	0.25
c	0.07	0.12	0.17
D	0.75	0.80	0.85
E	0.55	0.60	0.65
H	0.95	1.00	1.05
L	0.19 REF		
L2	0.05	0.10	0.15



RECOMMENDED MOUNTING FOOTPRINT

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC MARKING DIAGRAM*



STYLE 1 STYLE 2

X = Specific Device Code
M = Date Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, “G” or microdot “▪”, may or may not be present. Some products may not follow the Generic Marking.

STYLE 1:
PIN 1. CATHODE (POLARITY BAND)
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STYLE 2:
NO POLARITY

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DESCRIPTION:	**SOD−923 0.80x0.60x0.37**		**PAGE 1 OF 1**

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